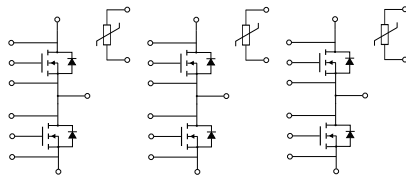



## Automotive-grade ACEPACK DRIVE power module, sixpack topology 1200 V, 2.55 mΩ typ. SiC MOSFET gen.3 based



ACEPACK DRIVE



### Features

- AQC 324 qualified 
- 1200 V blocking voltage
- 2.55 mΩ of typical  $R_{DS(on)}$
- Maximum operating junction temperature  $T_J = 175\text{ °C}$
- Very low switching energy
- Low inductive compact design for an higher power density
- $Si_3N_4$  AMB substrate to improve thermal performance
- SiC Power MOSFET chip sintered to substrate for improved lifetime
- 4.2 kV DC 1 s insulation
- Directly liquid cooled base plate with pin-fins
- Three integrated NTC temperature sensors

### Application

- Main inverter (electric traction)

### Description

The ACEPACK DRIVE is a compact sixpack module optimized for hybrid and electric vehicles traction inverter. This power module features switches based on silicon carbide Power MOSFET 3<sup>rd</sup> generation, are characterized by very low  $R_{DS(on)}$ , very limited switching losses and outstanding performances in synchronous rectification working mode. This will ensure superb efficiency in final application, saving battery recharging cycles.

A copper base plate with pin-fin base structure make direct fluid cooling available for this power module minimizing thermal resistance.

A dedicated pin-out has been developed to get the best switching performances and press-fit pins will ensure optimal connection with driving board.



#### Product status link

[ADP360120W3](#)

#### Product summary

<b>Order code</b>	ADP360120W3
<b>Marking</b>	ADP360120W3
<b>Package</b>	ACEPACK DRIVE
<b>Leads type</b>	Press-fit
<b>Packing</b>	Tray

# 1 Electrical ratings

**Table 1. Absolute maximum ratings of each switch**

Symbol	Parameter	Value	Unit
$V_{(BR)DSS}$	Drain-source breakdown voltage	1200	V
$V_{GS}$	Gate-source voltage	-10 to 22	V
	Gate-source voltage (recommended operating values)	-5 to 18	
$I_D^{(1)}$	Continuous drain current at $T_F = 75\text{ °C}$ (refer to $T_J \text{ max} = 175\text{ °C}$ , $V_{GS} = 18\text{ V}$ )	379	A
$I_{DM}^{(2)}$	Repetitive peak drain current	800	A
$P_{TOT}$	Total power dissipation at $T_F = 75\text{ °C}$ (refer to $T_J \text{ max} = 175\text{ °C}$ , $V_{GS} = 18\text{ V}$ )	704	W
$T_J$	Operative junction temperature range under switching conditions	-40 to 175 <sup>(3)</sup>	°C

1. Specified by design, not tested in production.
2. Pulse width limited by maximum junction temperature.
3. Maximum baseplate temperature has to be always limited to 125 °C.

**Table 2. Thermal data of each switch**

Symbol	Parameter	Min.	Typ.	Max.	Unit
$R_{thJF}^{(1)}$	Thermal resistance, junction-to-fluid (flow rate = 10 LPM, $T_F = 75\text{ °C}$ , single switch)	-	0.129	-	°C/W

1. Simulated value considering 50% water/ 50% ethylene glycol cooling fluid. Refer to TN1412 "ACEPACK DRIVE assembly instructions" for water jacket design.

## 2 Electrical characteristics

$T_J = 25\text{ °C}$ , unless otherwise specified.

**Table 3. Electrical characteristics of each switch**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$R_{DS(on)}^{(1)}$	Static drain-source on-resistance	$V_{GS} = 18\text{ V}, I_D = 360\text{ A}$		2.55	3.45	m $\Omega$
		$V_{GS} = 18\text{ V}, I_D = 360\text{ A}, T_J = 175\text{ °C}$		4.25		
		$V_{GS} = 18\text{ V}, I_D = -360\text{ A}$		2.4		
		$V_{GS} = 18\text{ V}, I_D = -360\text{ A}, T_J = 175\text{ °C}$		4.2		
$V_{GS(th)}$	Gate threshold voltage	$V_{DS} = V_{GS}, I_D = 40\text{ mA}$	1.9	3.1	4.4	V
$I_{DSS}$	Zero gate voltage drain current	$V_{GS} = 0\text{ V}, V_{DS} = 1200\text{ V}$			100	$\mu\text{A}$
		$V_{GS} = 0\text{ V}, V_{DS} = 1200\text{ V}, T_J = 150\text{ °C}^{(2)}$			2	mA
$I_{GSS}$	Gate-body leakage current	$V_{DS} = 0\text{ V}, V_{GS} = -10\text{ to }22\text{ V}$			2	$\mu\text{A}$
$C_{iss}$	Input capacitance	$V_{DS} = 800\text{ V}, f = 1\text{ MHz}, V_{GS} = 0\text{ V}$		28.07		nF
$C_{oss}$	Output capacitance			1.07		
$C_{riss}$	Reverse transfer capacitance			0.09		
$Q_g$	Total gate charge	$V_{DS} = 800\text{ V}, I_D = 360\text{ A},$ $V_{GS} = -5\text{ V to }18\text{ V}$		944		nC
$Q_{gs}$	Gate-source charge			323		
$Q_{gd}$	Gate-drain charge			302		

- $R_{DS(on)}$  is referred to switch level.
- Specified by design, not tested in production.

**Table 4. Switching energy of each switch**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$E_{on}^{(1)}$	Turn-on switching energy	$V_{DD} = 800\text{ V}, V_{GS} = -5\text{ to }18\text{ V},$ $di/dt_{on} = 4.3\text{ A/ns}, R_{G-ON} = 10\text{ }\Omega,$ $R_{G-OFF} = 6.8\text{ }\Omega, I_D = 360\text{ A}$	-	24.7	-	mJ
		$V_{DD} = 800\text{ V}, V_{GS} = -5\text{ to }18\text{ V},$ $di/dt_{on} = 5.1\text{ A/ns}, R_{G-ON} = 10\text{ }\Omega,$ $R_{G-OFF} = 6.8\text{ }\Omega, I_D = 360\text{ A}, T_J = 175\text{ °C}$	-	21.3	-	
$E_{off}$	Turn-off switching energy	$V_{DD} = 800\text{ V}, V_{GS} = -5\text{ to }18\text{ V},$ $dv/dt_{off} = 8.3\text{ V/ns}, R_{G-ON} = 10\text{ }\Omega,$ $R_{G-OFF} = 6.8\text{ }\Omega, I_D = 360\text{ A}$	-	18.1	-	mJ
		$V_{DD} = 800\text{ V}, V_{GS} = -5\text{ to }18\text{ V},$ $dv/dt_{off} = 9.4\text{ V/ns}, R_{G-ON} = 10\text{ }\Omega,$ $R_{G-OFF} = 6.8\text{ }\Omega, I_D = 360\text{ A}, T_J = 175\text{ °C}$	-	18.7	-	

- Using active Miller clamp circuit.

**Table 5. Source-drain diode characteristics of each switch**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{SD}$	Forward on voltage drop	$V_{GS} = -5\text{ V}$ , $I_{SD} = 360\text{ A}$	-	4.3	-	V
$t_{rr}$	Reverse recovery time	$V_{DD} = 800\text{ V}$ , $V_{GS} = -5\text{ to }18\text{ V}$ , $R_{G-ON} = 10\ \Omega$ , $R_{G-OFF} = 6.8\ \Omega$ , $di/dt_{on} = 4.3\text{ A/ns}$ , $I_{SD} = 360\text{ A}$	-	33.4	-	ns
$Q_{rr}$	Reverse recovery charge		-	1.97	-	$\mu\text{C}$
$I_{RRM}$	Reverse recovery current		-	102	-	A
$E_{rec}$	Reverse recovery energy		-	0.36	-	mJ
$t_{rr}$	Reverse recovery time		$V_{DD} = 800\text{ V}$ , $V_{GS} = -5\text{ to }18\text{ V}$ ,	-	57	-
$Q_{rr}$	Reverse recovery charge	$R_{G-ON} = 10\ \Omega$ , $R_{G-OFF} = 6.8\ \Omega$ ,	-	5.5	-	$\mu\text{C}$
$I_{RRM}$	Reverse recovery current	$di/dt_{on} = 5.1\text{ A/ns}$ , $I_{SD} = 360\text{ A}$ ,	-	164	-	A
$E_{rec}$	Reverse recovery energy	$T_J = 175\text{ }^\circ\text{C}$	-	1.54	-	mJ

Note: Values are calculated taking in account an active Miller clamp circuit.

### 3 NTC

**Table 6. Absolute maximum ratings for NTC temperature sensor, considered as stand-alone**

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
R <sub>25</sub>	Resistance	T = 25 °C		5.0		kΩ
R <sub>100</sub>	Resistance	T = 100 °C		493		Ω
ΔR/R	Deviation of R <sub>100</sub>		-5		+5	%
B <sub>25/50</sub>	B-constant			3375		K
B <sub>25/80</sub>				3411		

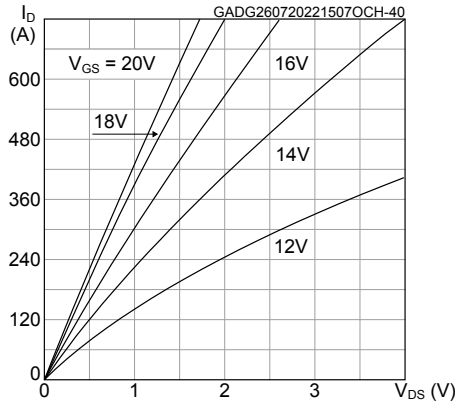
## 4 ACEPACK DRIVE power module details

**Table 7. Ratings for module**

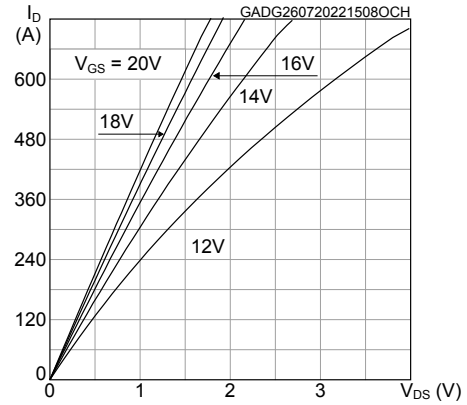
Symbol	Parameter		Value	Unit
$V_{ISO}$	Isolation voltage (f = 0 Hz, t = 1 s)		4.2	kV
	Internal isolation (class 1, IEC 61140)		$Si_3N_4$	
	Baseplate module material		Ni plated, Cu baseplate	
$d_{creep}$	Creepage distance	Terminal to heat sink	9.0	mm
		Terminal to terminal	9.0	
$d_{clear}$	Clearance distance	Terminal to heat sink	4.5	mm
		Terminal to terminal	4.5	
CTI	Comparative tracking index		>200	
$L_s$	Typical stray inductance drain to source module loop		10	nH
$R_s$	Typical module lead resistance, terminals to chip		0.5	m $\Omega$
$T_{stg}$	Storage temperature range		-40 to 125	$^{\circ}C$

## 5 Electrical characteristics (curves)

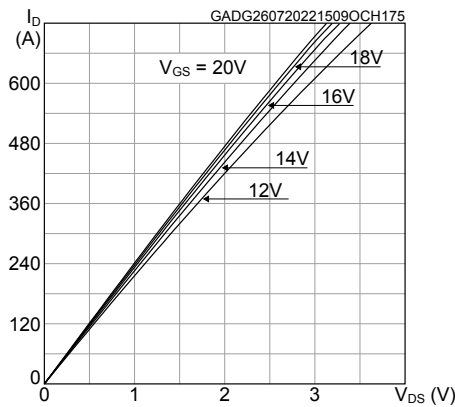
**Figure 1. Typical output characteristics ( $T_J = -40^\circ\text{C}$ )**



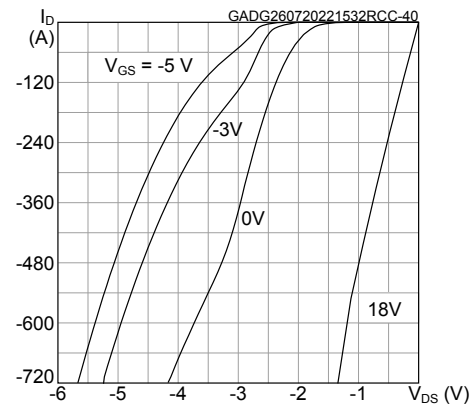
**Figure 2. Typical output characteristics ( $T_J = 25^\circ\text{C}$ )**



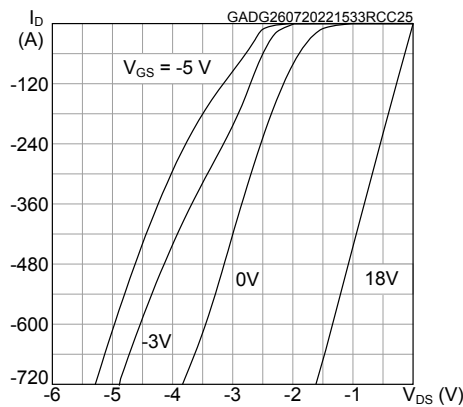
**Figure 3. Typical output characteristics ( $T_J = 175^\circ\text{C}$ )**



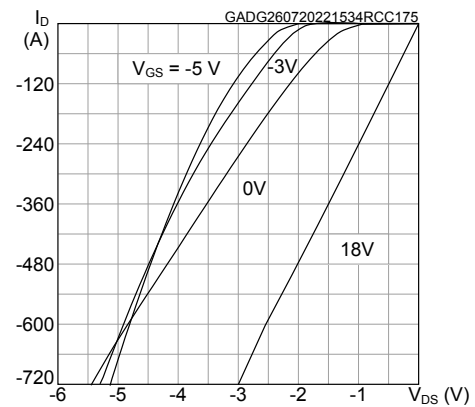
**Figure 4. Typical reverse conduction characteristics ( $T_J = -40^\circ\text{C}$ )**



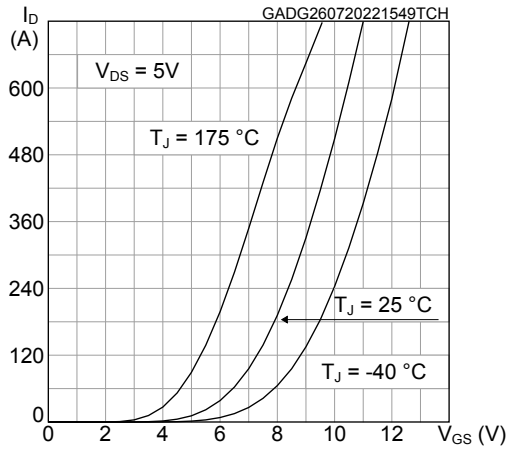
**Figure 5. Typical reverse conduction characteristics ( $T_J = 25^\circ\text{C}$ )**



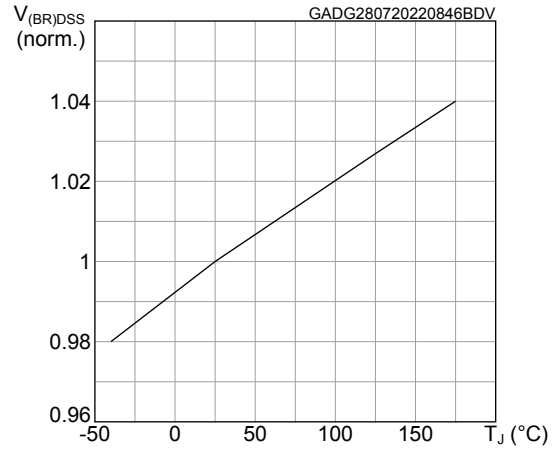
**Figure 6. Typical reverse conduction characteristics ( $T_J = 175^\circ\text{C}$ )**



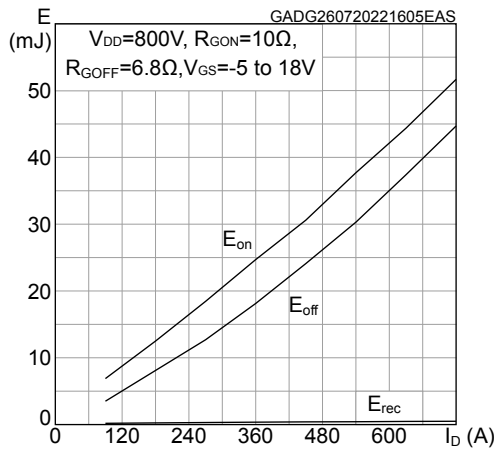
**Figure 7. Typical transfer characteristics**



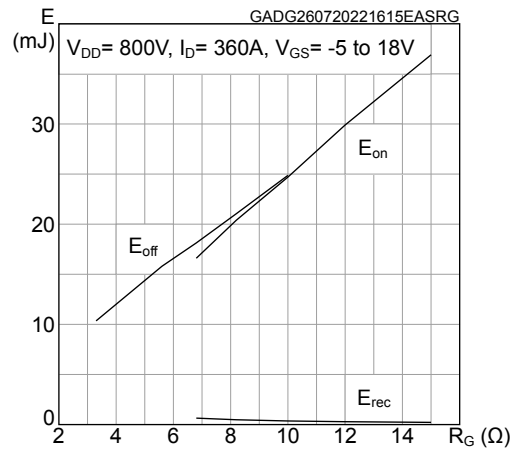
**Figure 8. Normalized breakdown voltage vs temperature**



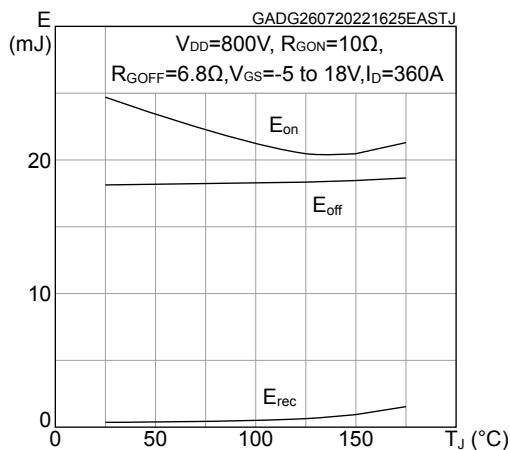
**Figure 9. Typical switching energy vs drain current**



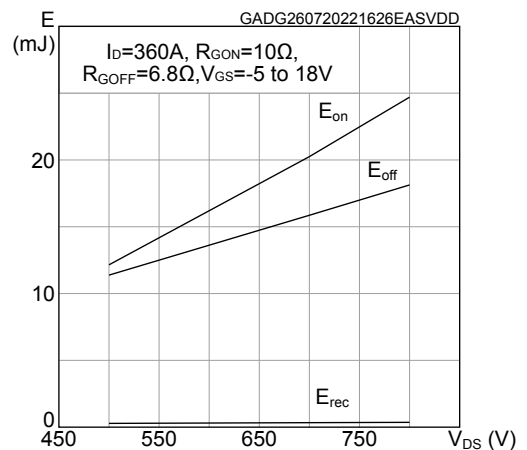
**Figure 10. Typical switching energy vs gate resistance**



**Figure 11. Typical switching energy vs temperature**

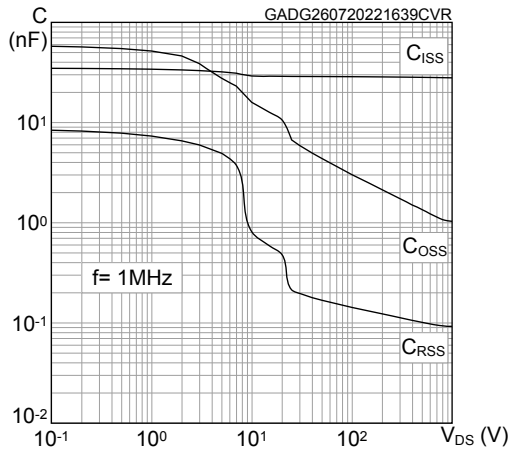


**Figure 12. Typical switching energy vs bus voltage**

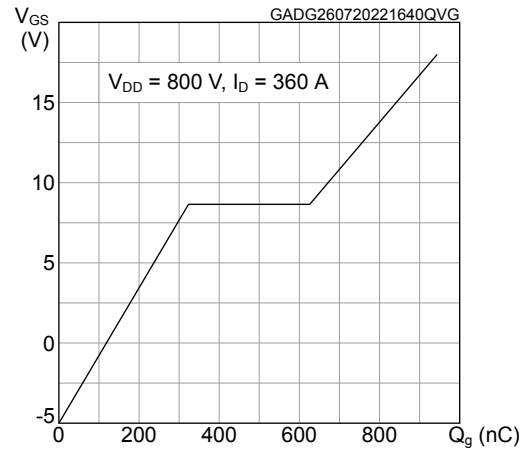




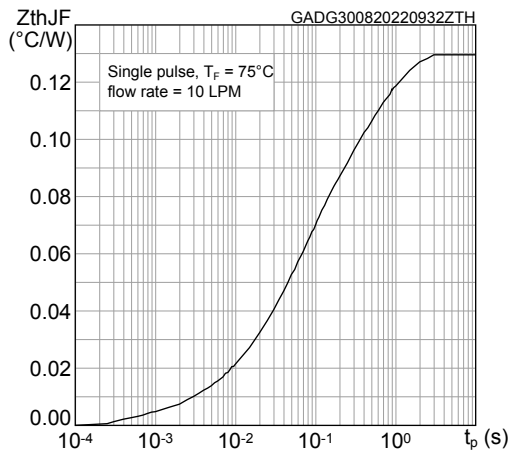
**Figure 13. Typical capacitance characteristics**



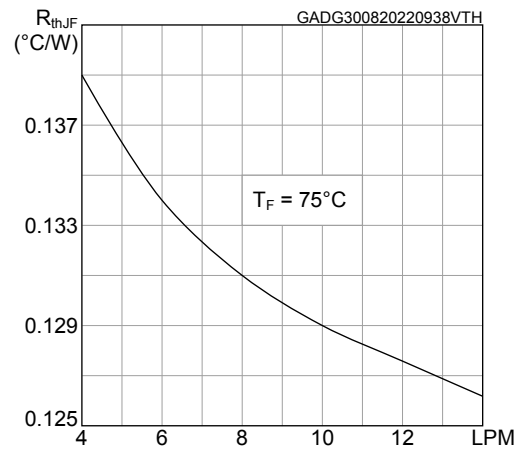
**Figure 14. Typical gate charge characteristics**



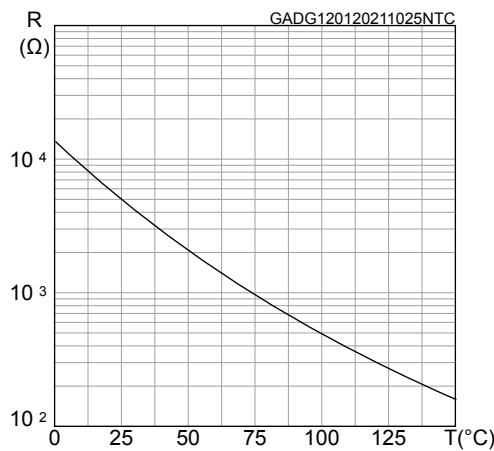
**Figure 15. Typical transient thermal impedance**



**Figure 16. Typical thermal resistance vs flow rate**



**Figure 17. Typical NTC resistance vs temperature**



## 6 Topology, pin description and positioning

Figure 18. Topology, pin description and positioning

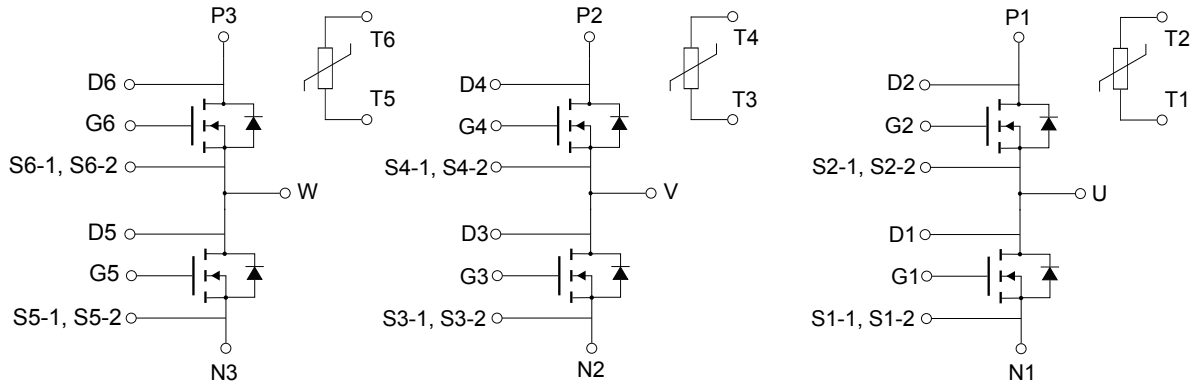
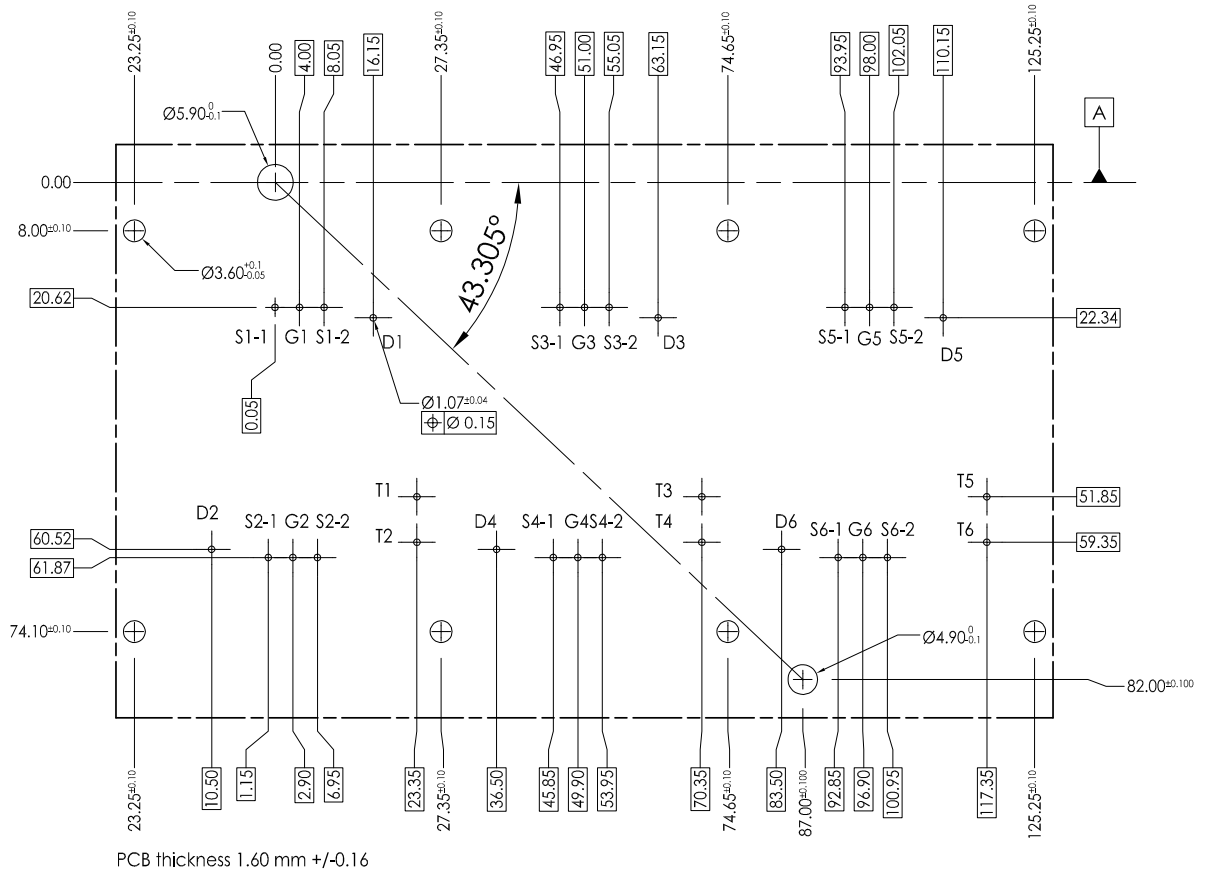


Figure 19. ACEPACK DRIVE PCB drawing (dimensions are in mm.)



DM00518615\_PCB\_Rev5

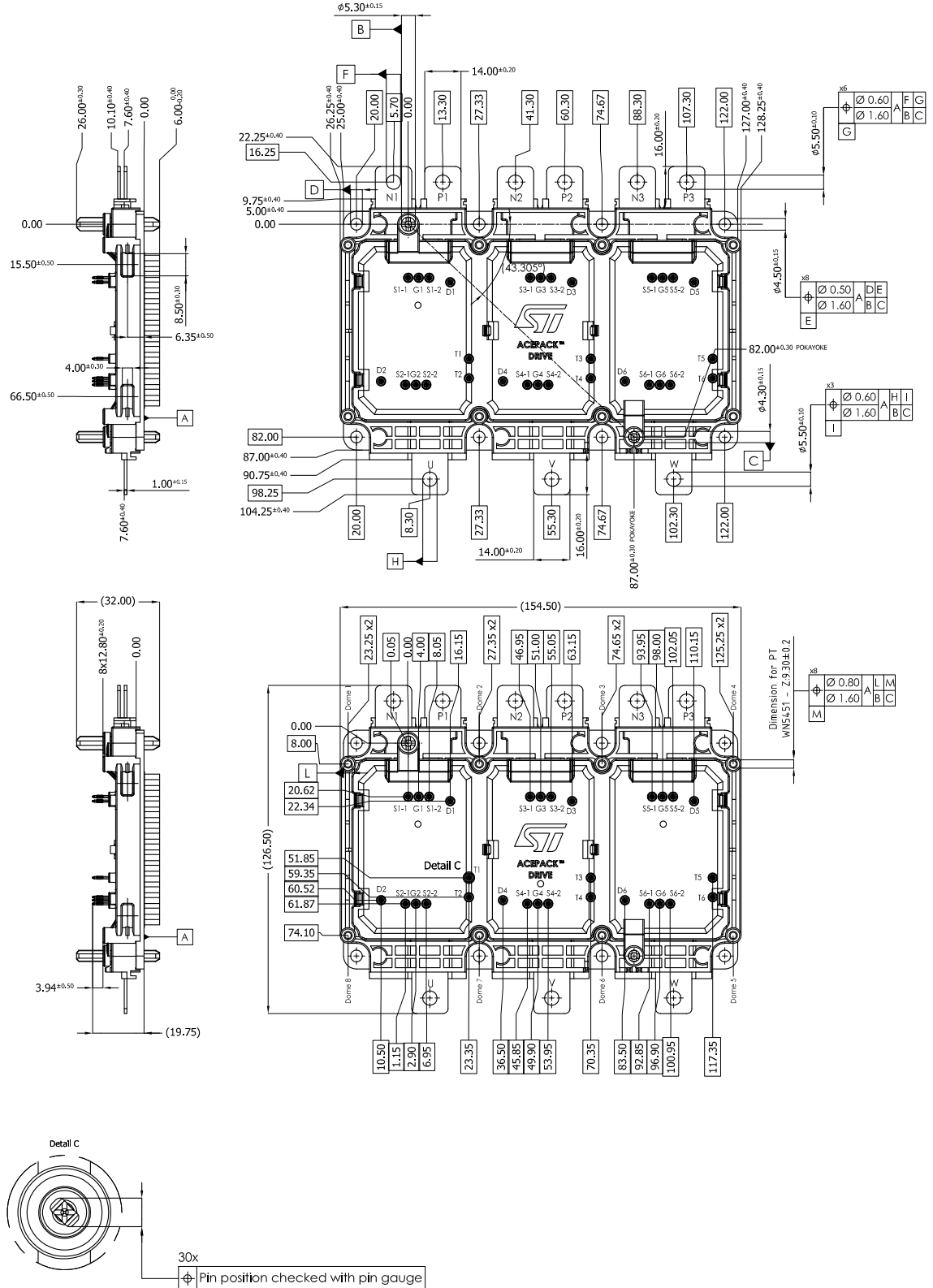
## **7** Package information

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In order to meet environmental requirements, ST offers these devices in different grades of **ECOPACK** packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK is an ST trademark.

## 7.1 ACEPACK DRIVE package information

Figure 20. ACEPACK DRIVE short tab package outline (dimensions are in mm.)



DM00518615\_Rev5

## Revision history

**Table 8. Document revision history**

Date	Revision	Changes
06-Sep-2021	1	First release.
02-Aug-2022	2	<p>Removed <i>Section 1.1 Inverter switch</i>, inserted and updated <i>Table 1. Absolute maximum ratings of each switch</i>, added <i>Table 2. Thermal data of each switch</i> under the <i>Section 1 Electrical ratings</i>.</p> <p>Inserted and updated <i>Table 3. Electrical characteristics of each switch</i>, added <i>Table 4. Switching energy of each switch</i> and updated <i>Table 5. Source-drain diode characteristics of each switch</i> under <i>Section 2 Electrical characteristics</i>.</p> <p>Updated <i>Table 6. Absolute maximum ratings for NTC temperature sensor, considered as stand-alone</i>.</p> <p>Updated <i>Figure 20. ACEPACK DRIVE short tab package outline (dimensions are in mm.)</i>.</p> <p>Inserted <i>Section 5 Electrical characteristics (curves)</i>.</p> <p>Minor text changes.</p>
06-Sep-2022	3	<p>Updated <i>Section 1 Electrical ratings, Section 5 Electrical characteristics (curves)</i> and <i>Section 7.1 ACEPACK DRIVE package information</i>.</p> <p>Minor text changes.</p>
19-Oct-2022	4	Updated <i>Table 2. Thermal data of each switch</i> .

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